

5-V Low-Drop Fixed Voltage Regulator

TLE 4269

Features

- Output voltage tolerance ≤ ± 2 %
- 150 mA current capability
- Very low current consumption
- Early warning
- Reset output low down to $V_{\rm O}$ = 1 V
- Overtemperature protection
- Reverse polarity proof
- Adjustable reset threshold
- Very low drop voltage
- Wide temperature range
- Integrated pull up resistor at logic outputs

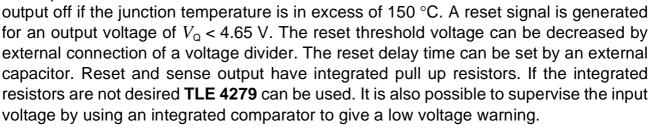
Туре	Ordering Code	Package
TLE 4269 G	Q67006-A9173-A201K5	P-DSO-8-3
TLE 4269 GM	Q67006-A9288-A201K5	P-DSO-14-8
TLE 4269 GL	Q67006-A9192-C703	P-DSO-20-17

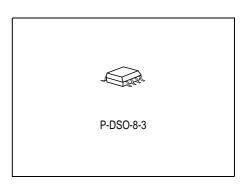


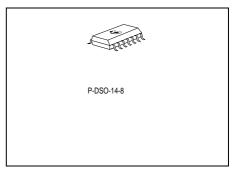
SMD type

Functional Description

This device an automotive suited voltage regulator with a fixed 5-V output. The maximum operating voltage is 45 V. The output is able to drive 150 mA load. It is short circuit protected and the thermal shutdown switches the











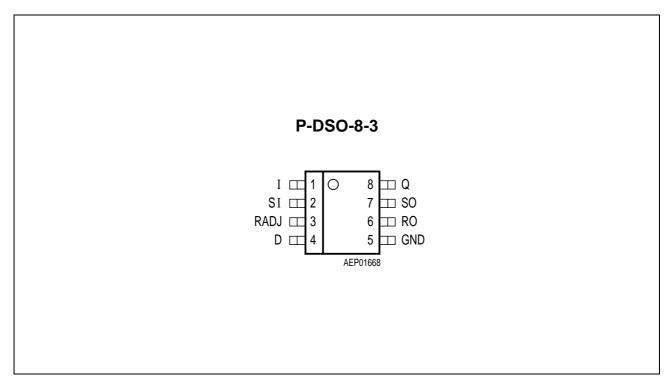


Figure 1 Pin Configuration (top view)

Pin Definitions and Functions (TLE 4269 G)

Pin No.	Symbol	Function
1	I	Input; block to GND directly at the IC with a ceramic capacitor.
2	SI	Sense Input; if not needed connect to Q.
3	RADJ	Reset Threshold Adjust; if not needed connect to GND.
4	D	Reset Delay; to select delay time, connect to GND via capacitor.
5	GND	Ground
6	RO	Reset Output; the open-collector output is internally linked to Q via a 20 k Ω pull-up resistor. Keep open, if not needed.
7	SO	Sense Output; the open-collector output is internally linked to the output via a 20 k Ω pull-up resistor. Keep open, if not needed.
8	Q	5-V Output ; connect to GND with a 10 μF capacitor, ESR < 10 Ω .



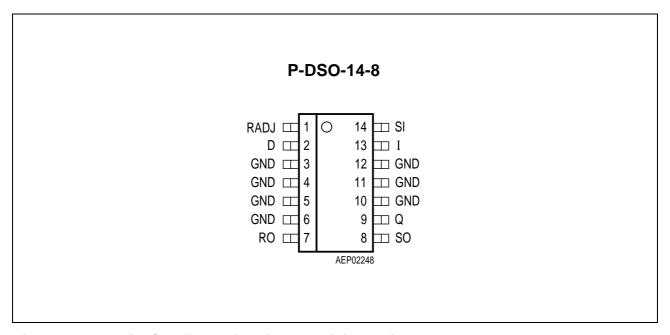


Figure 2 Pin Configuration (top view) (cont'd)

Pin Definitions and Functions (TLE 4269 GM)

Pin No.	Symbol	Function
1	RADJ	Reset Threshold Adjust; if not needed connect to GND.
2	D	Reset Delay; to select delay time; connect to GND via capacitor.
3, 4, 5, 6	GND	Ground
7	RO	Reset Output; open-collector output, internally connected to Q via a pull-up resistor of 20 k Ω . Keep open, if not needed.
8	SO	Sense Output; open-collector output, internally connected to Q via a 20 k Ω pull-up resistor. Keep open, if not needed.
9	Q	5-V Output; connect to GND with a 10 μF capacitor, ESR < 10 Ω .
10, 11, 12	GND	Ground
13	I	Input; block to GND directly at the IC with a ceramic capacitor.
14	SI	Sense Input; if not needed connect to Q.



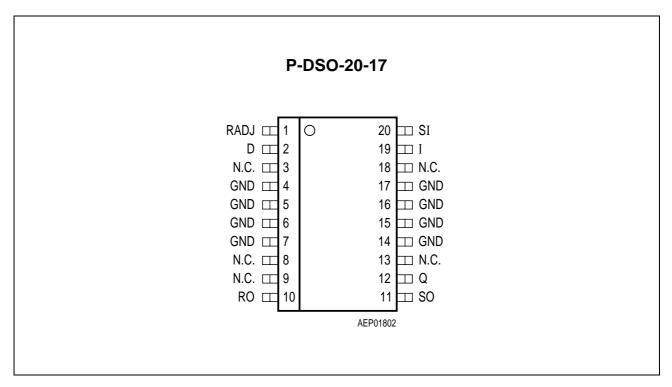


Figure 3 Pin Configuration (top view) (cont'd)

Pin Definitions and Functions (TLE 4269 GL)

Pin No.	Symbol	Function
1	RADJ	Reset Threshold Adjust; if not needed connect to ground.
2	D	Reset Delay; to select delay time, connect to GND via external capacitor.
4-7, 14-17	GND	Ground
10	RO	Reset Output; the open-collector output is internally linked to Q via a 20 k Ω pull-up resistor. Keep open, if not needed.
11	SO	Sense Output; the open-collector output is internally linked to the output via a 20 k Ω pull-up resistor. Keep open, if not needed.
12	Q	Output; connect to GND with a 10 μF capacitor, ESR < 10 Ω .
19	I	Input; block directly at the IC by a ceramic capacitor.
20	SI	Sense Input; if not needed connect to Q.



Circuit Description

The control amplifier compares a reference voltage, made highly accurate by resistance balancing, with a voltage proportional to the output voltage and drives the base of the series PNP transistor via a buffer. Saturation control as a function of the load current prevents any over-saturation of the power element.

The reset output RO is in high-state if the voltage on the delay capacitor $C_{\rm D}$ is greater or equal $V_{\rm UD}$. The delay capacitor $C_{\rm D}$ is charged with the current $I_{\rm D}$ for output voltages greater than the reset threshold $V_{\rm RT}$. If the output voltage gets lower than $V_{\rm RT}$ ('reset condition') a fast discharge of the delay capacitor $C_{\rm D}$ sets in and as soon as $V_{\rm D}$ gets lower than $V_{\rm LD}$ the reset output RO is set to low-level.

The time gap for the delay capacitor discharge is the reset reaction time t_{RR} .

The reset threshold $V_{\rm RT}$ can be decreased via an external voltage divider connected to the pin RADJ. In this case the reset condition is reached if $V_{\rm Q} < V_{\rm RT}$ and $V_{\rm RADJ} < V_{\rm RAQDJ,\,TH}$. Dimensioning the voltage divider (see **Figure 5**) according to

$$V_{\text{THRES}} = V_{\text{RADJ,TH}} \times (R_{\text{ADJ1}} + R_{\text{ADJ2}}) / R_{\text{ADJ2}},$$

the reset threshold can be decreased down to 3.5 V. If the reset-adjust-option is not needed the RADJ-pin should be connected to GND causing the reset threshold to go to its default value (typ. 4.65 V).

A built in comparator compares the signal of the pin SI, normally fed by a voltage divider from the input voltage, with the reference and gives an early warning on the pin SO. It is also possible to superwise another voltage e.g. of a second regulator, or to build a watchdog circuit with few external components.

Application Description

The input capacitor $C_{\rm l}$ is necessary for compensating line influences. Using a resistor of approx. 1 Ω in series with $C_{\rm l}$, the oscillating circuit consisting of input inductivity and input capacitance can be damped. The output capacitor $C_{\rm Q}$ is necessary for the stability of the regulating circuit. Stability is guaranteed at values \geq 10 μ F and an ESR \leq 10 Ω within the operating temperature range. For small tolerances of the reset delay the spread of the capacitance of the delay capacitor and its temperature coefficient should be noted.

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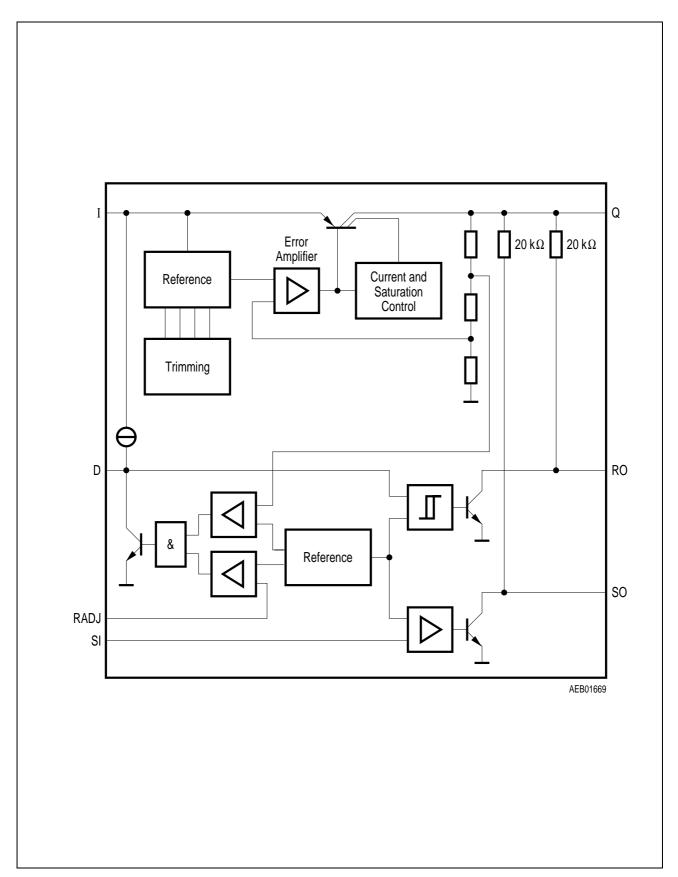


Figure 4 Block Diagram



Absolute Maximum Ratings

 $T_{\rm i}$ = -40 to 150 °C

Parameter	Symbol	Limi	t Values	Unit	Notes
		min.	max.		
Input					
Input voltage	$V_{\scriptscriptstyle m I}$	- 40	45	V	_
Input current	I_{I}	_	_	_	internal limited
Sense Input					
Input voltage	$V_{\mathtt{SI}}$	- 40	45	V	-
Input current	$I_{ m SI}$	1	1	mA	-
Reset Threshold					
Voltage	V_{RADJ}	- 0.3	7	V	_
Current	I_{RADJ}	- 10	10	mA	_
Reset Delay					
Voltage	V_{D}	- 0.3	7	V	-
Current	I_{D}	_	_	_	internal limited
Ground					
Current	I_{GND}	50	_	mA	_
Reset Output	,	•	•	•	·
Voltage	V_{R}	- 0.3	7	V	_
Current	I_{R}	_	_	_	internal limited



Absolute Maximum Ratings (cont'd) $T_i = -40$ to 150 °C

Parameter	Symbol	Limi	t Values	Unit	Notes
		min.	max.		
Sense Output					
Voltage	V_{SO}	- 0.3	7	V	_
Current	I_{SO}	_	_	_	internal limited
5-V Output					
Output voltage	V_{Q}	- 0.5	7	V	_
Output current	I_{Q}	- 10	_	mA	_
Temperature					
Junction temperature	T_{j}	_	150	°C	_
Storage temperature	T_{Stg}	- 50	150	°C	_
Operating Range					
Input voltage	$V_{\scriptscriptstyle m I}$	_	45	V	_
Junction temperature	$T_{ m j}$	- 40	150	°C	_
Thermal Data					
Junction-ambient	R_{thja}	_	200 70 70	K/W K/W K/W	P-DSO-8-3 P-DSO-14-8 P-DSO-20-17
Junction-pin	R_{thjp}	_	30 30	K/W K/W	P-DSO-14-8 ¹⁾ P-DSO-20-17 ¹

¹⁾ Measured to Pin 4



Characteristics

 $V_{\rm I}$ = 13.5 V; $T_{\rm j}$ = – 40 °C < $T_{\rm j}$ < 125 °C

Parameter	Symbol	Limit Values			Unit	Measuring
		min.	typ.	max.		Condition
Output voltage	V_{Q}	4.90	5.00	5.10	V	1 mA $\leq I_{Q} \leq$ 100 mA 6 V $\leq V_{I} \leq$ 16 V
Current limit	I_{Q}	150	200	500	mA	_
Current consumption; $I_{q} = I_{l} - I_{Q}$	I_{q}	-	240	300	μΑ	$I_{\rm Q} \le$ 1 mA, $T_{\rm j} <$ 85 °C
Current consumption; $I_{q} = I_{l} - I_{Q}$	I_{q}	_	250	700	μΑ	$I_{\rm Q}$ = 10 mA
Current consumption; $I_{q} = I_{l} - I_{Q}$	I_{q}	_	2	8	mA	$I_{\rm Q}$ = 50 mA
Drop voltage	V_{dr}	_	0.25	0.5	V	$I_{\rm Q}$ = 100 mA ¹⁾
Load regulation	ΔV_{Q}	_	10	30	mV	$I_{\rm Q}$ = 5 mA to 100 mA
Line regulation	ΔV_{Q}	_	10	40	mV	$V_{\rm I}$ = 6 V to 26 V $I_{\rm Q}$ = 1 mA
Reset Generator						
Switching threshold	V_{RT}	4.50	4.65	4.80	V	_
Reset adjust switching threshold	$V_{RADJ,TH}$	1.26	1.35	1.44	V	V _Q > 3.5 V
Reset pull up	_	10	20	40	kΩ	_
Saturation voltage	$V_{RO,SAT}$	_	0.1	0.4	V	R _{intern}
Upper delay switching threshold	$V_{\sf UD}$	1.4	1.8	2.2	V	_
Lower delay switching threshold	V_{LD}	0.3	0.45	0.60	V	_
Saturation voltage delay capacitor	$V_{ extsf{D, SAT}}$	-	_	0.1	V	$V_{\rm Q} < V_{\rm RT}$



Characteristics (cont'd)

 $V_1 = 13.5 \text{ V}; T_1 = -40 \text{ °C} < T_1 < 125 \text{ °C}$

Symbol	Limit Values		Unit	Measuring	
	min.	typ.	max.		Condition
I_{D}	3.0	6.5	9.5	μΑ	$V_{\rm D}$ = 1 V
t _d	17	28	_	ms	$C_{\rm D} = 100 \; {\rm nF}$
t_{t}	_	1	_	μs	$C_{\rm D} = 100 \; {\rm nF}$
	I_{D} t_{d}	I_D 3.0 t_d 17	min. typ. I_D 3.0 6.5 t_d 17 28	min. typ. max. I_D 3.0 6.5 9.5 t_d 17 28 -	min. typ. max. I_D 3.0 6.5 9.5 μA t_d 17 28 - ms

Input Voltage Sense

Sense threshold high	$V_{\sf SI,\; high}$	1.24	1.31	1.38	V	-
Sense threshold low	$V_{SI,low}$	1.16	1.20	1.28	V	-
Sense output low voltage	$V_{SO,low}$	_	0.1	0.4	V	$V_{\rm SI}$ < 1.20 V; $V_{\rm Q}$ > 3 V $R_{\rm intern}$
Sense pull up	_	10	20	40	kΩ	-
Sense input current	I_{SI}	- 1	0.1	1	μΑ	-

¹⁾ Drop voltage = $V_{\rm I}$ – $V_{\rm Q}$ measured when the output voltage has dropped 100 mV from the nominal value obtained at 13.5 V input.



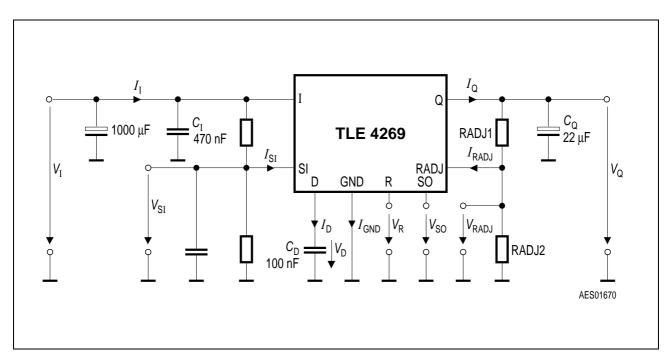


Figure 5 Measuring Circuit

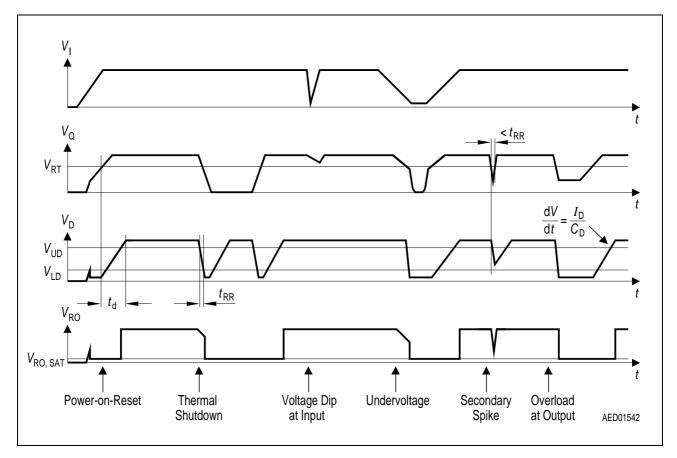


Figure 6 Reset Timing Diagram



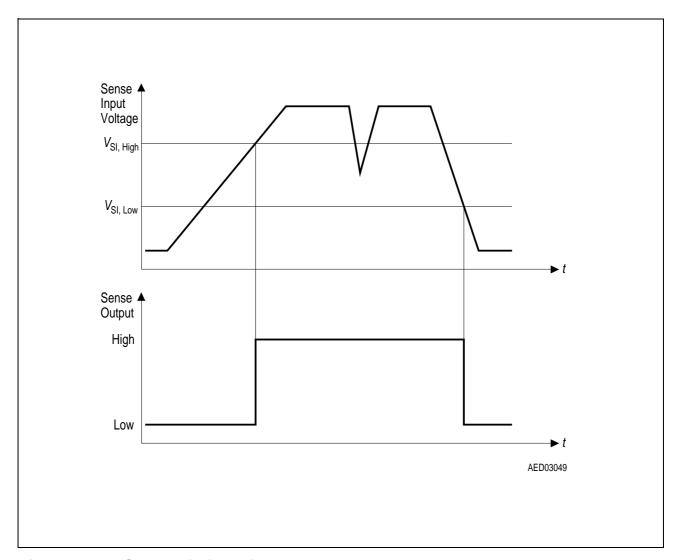
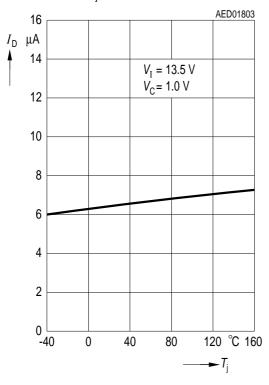


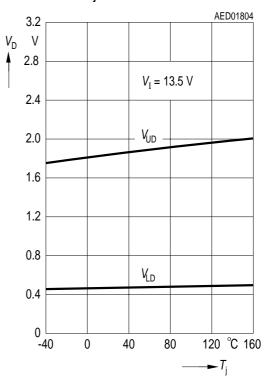
Figure 7 Sense Timing Diagram



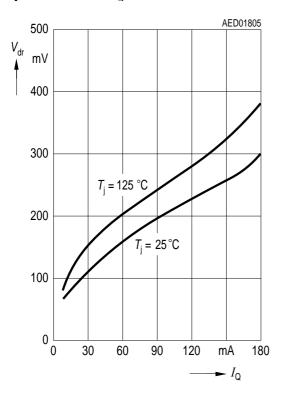
Charge Current I_D versus Temperature T_i



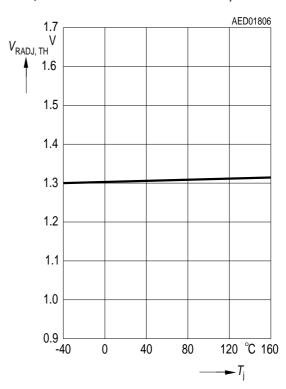
Switching Voltage $V_{\rm UD}$ and $V_{\rm LD}$ versus Temperature $T_{\rm i}$



Drop Voltage $V_{\rm dr}$ versus Output Current $I_{\rm Q}$

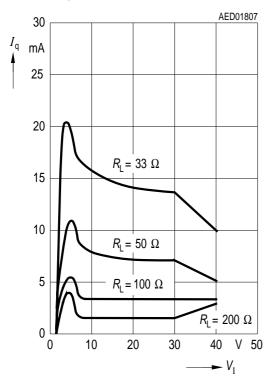


Reset Adjust Switching Threshold $V_{\mathsf{RADJ},\mathsf{TH}}$ versus Temperature T_{i}

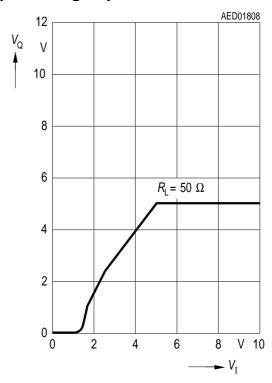




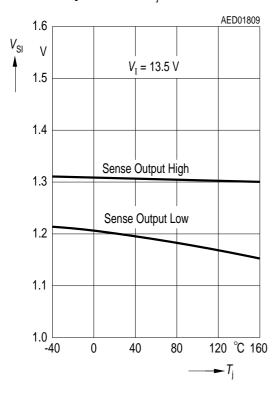
Current Consumption $I_{\rm Q}$ versus Input Voltage $V_{\rm I}$



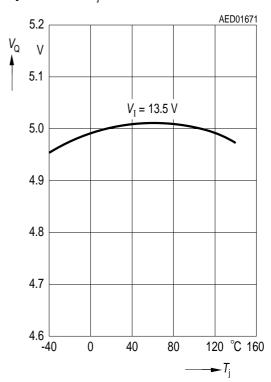
Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$



Sense Threshold V_{si} versus Temperature T_i

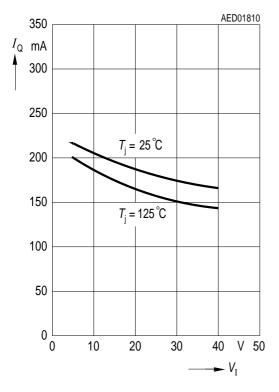


Output Voltage $V_{\rm Q}$ versus Temperature $T_{\rm j}$

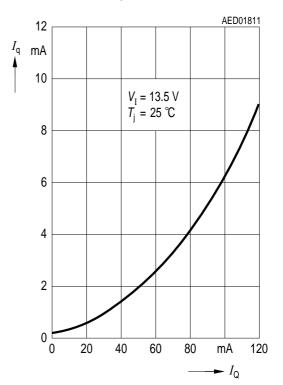




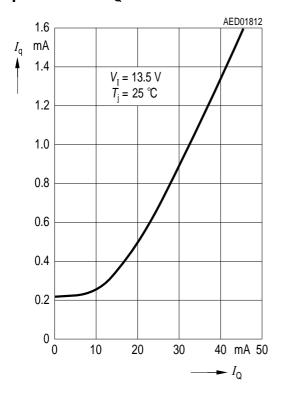
Output Current $I_{\rm Q}$ versus Input Voltage $V_{\rm I}$



Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$

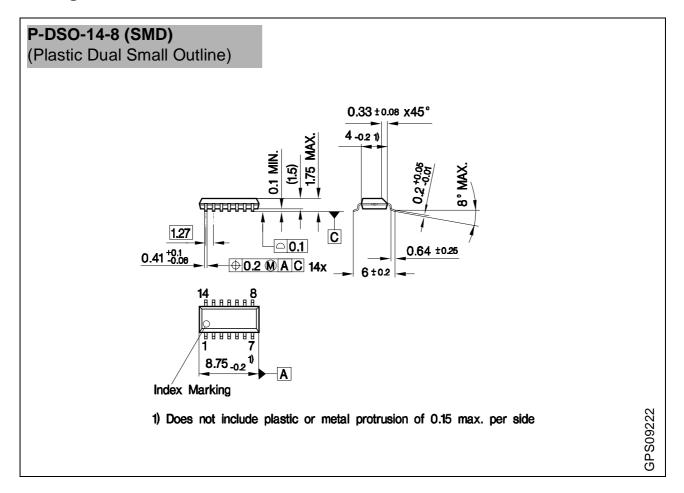


Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$





Package Outlines



Sorts of Packing

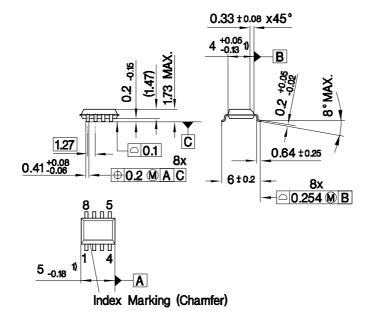
Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

SMD = Surface Mounted Device

Dimensions in mm



P-DSO-8-3 (SMD) (Plastic Dual Small Outline)



1) Does not include plastic or metal protrusion of 0.15 max. per side

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

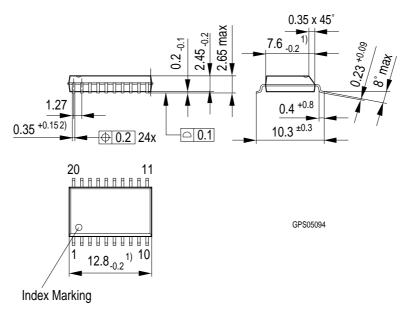
SMD = Surface Mounted Device

Dimensions in mm



P-DSO-20-17 (SMD)

(Plastic Dual Small Outline)



- 1) Does not include plastic or metal protrusions of 0.15 max per side
- 2) Does not include dambar protrusion of 0.05 max per side

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information"

SMD = Surface Mounted Device

Dimensions in mm



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